

Device Modeling Report

COMPONENTS:

DIODE/ GENERAL PURPOSE RECTIFIER/ PROFESSIONAL

PART NUMBER: 5GLZ47A

MANUFACTURER: TOSHIBA

REMARK: TC=150C

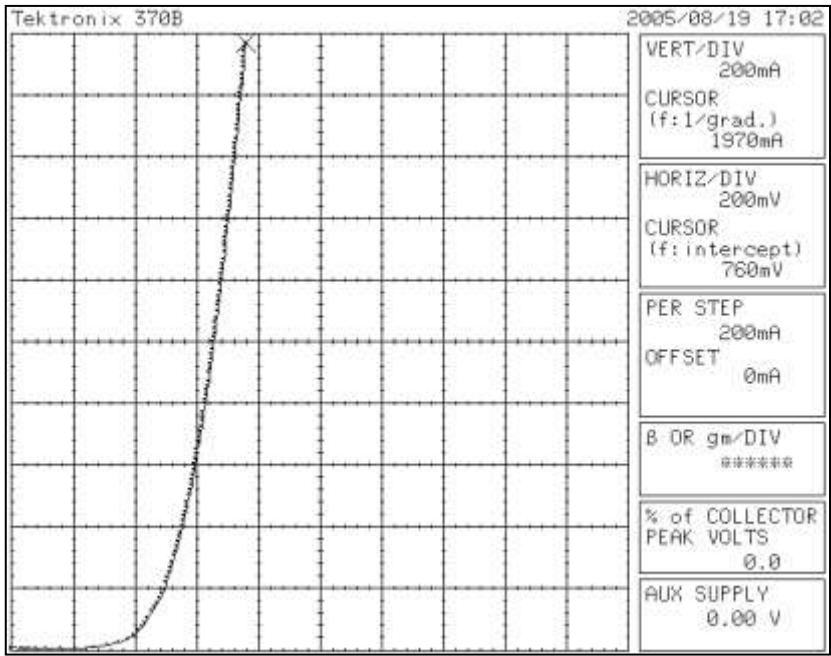


Bee Technologies Inc.

PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

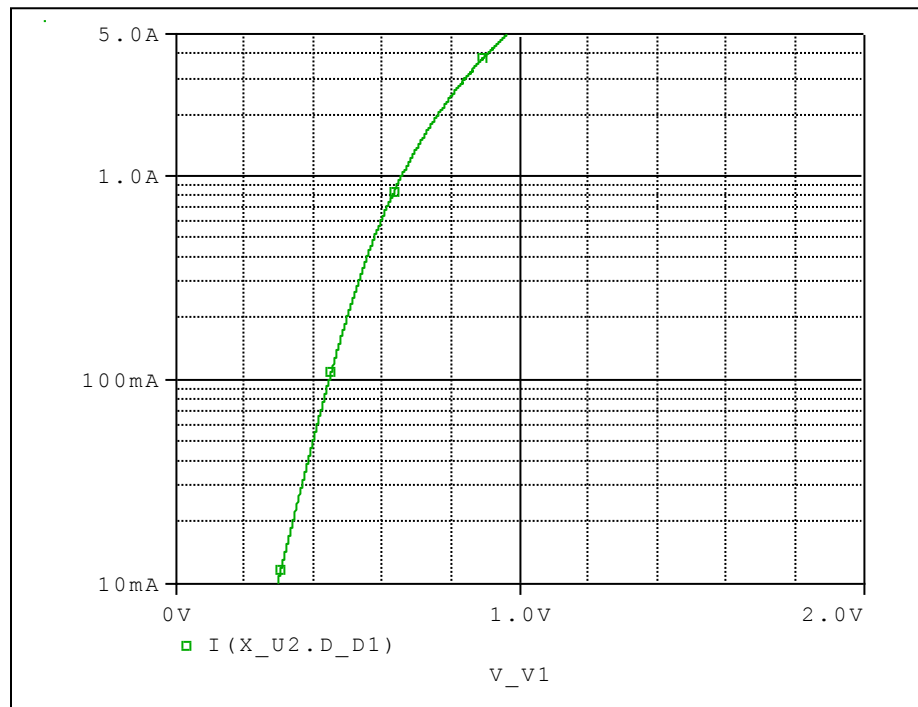
Forward Current Characteristic

Reference

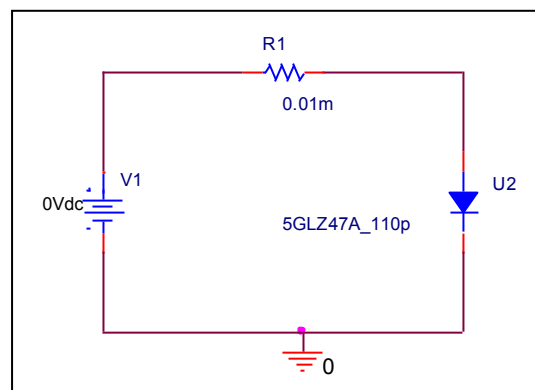


Forward Current Characteristic

Circuit Simulation Result

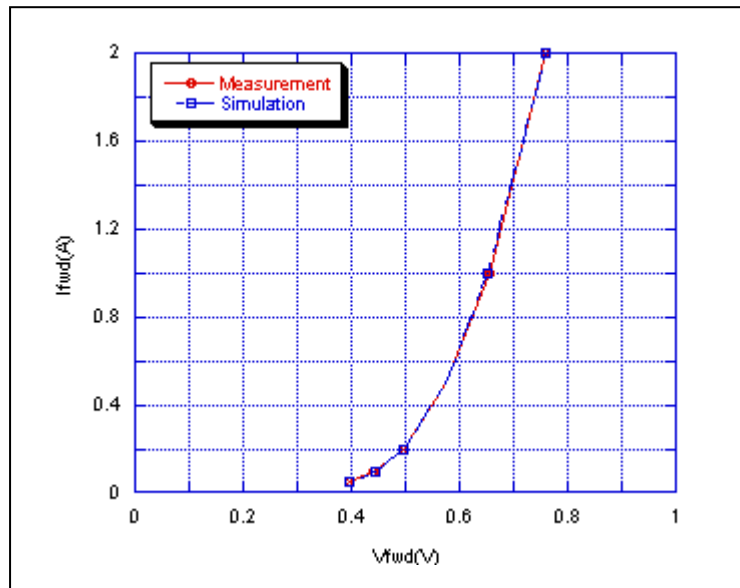


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

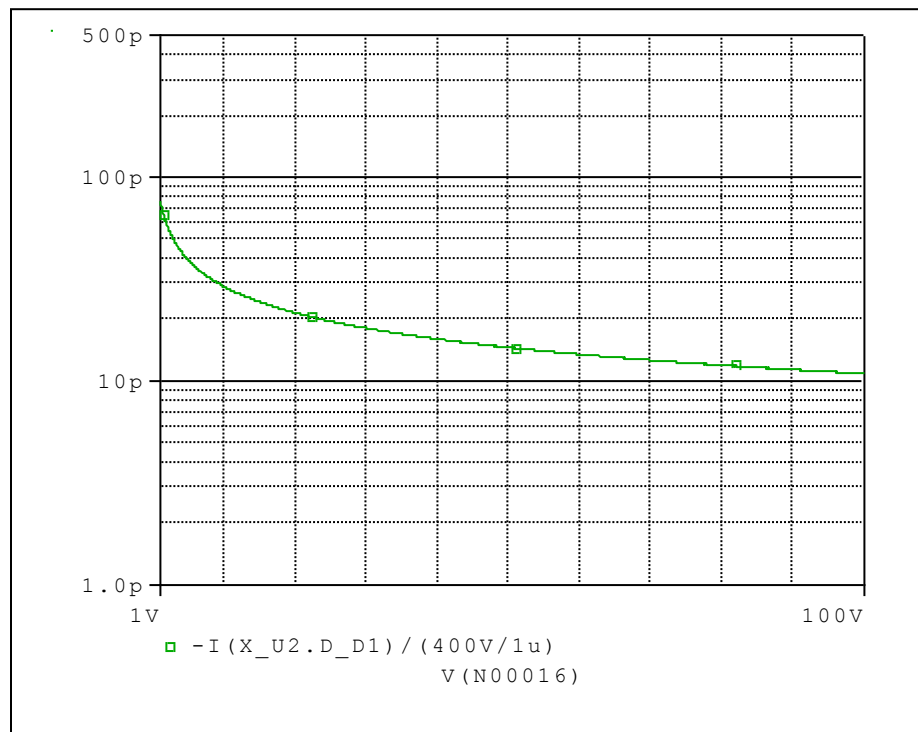


Simulation Result

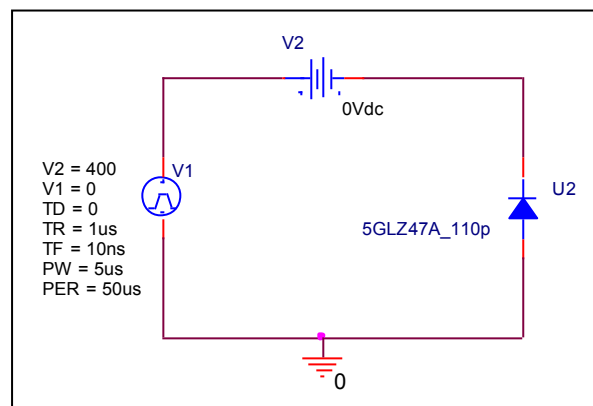
I_{fwd} (A)	V_{fwd} (V) Measurement	V_{fwd} (V) Simulation	%Error
0.05	0.398	0.397	0.251
0.1	0.442	0.444	-0.452
0.2	0.496	0.495	0.202
0.5	0.576	0.575	0.174
1	0.654	0.653	0.153
2	0.760	0.755	0.658

Capacitance Characteristic

Circuit Simulation Result

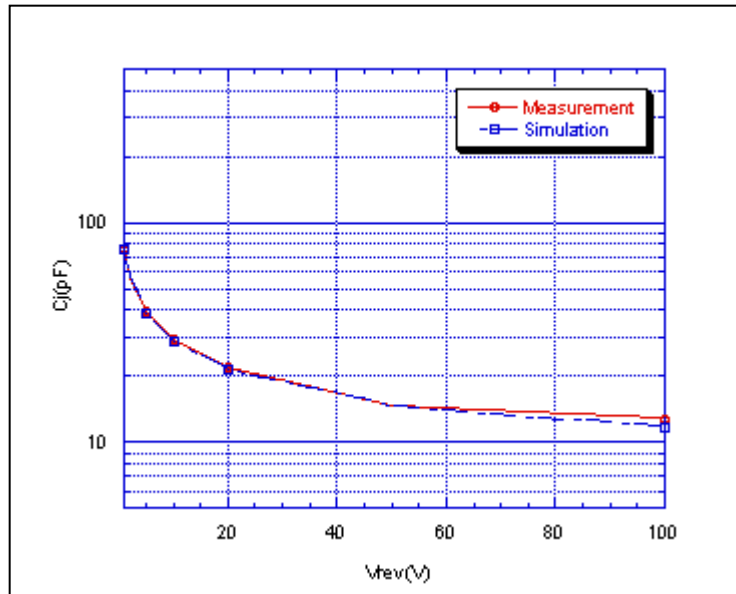


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

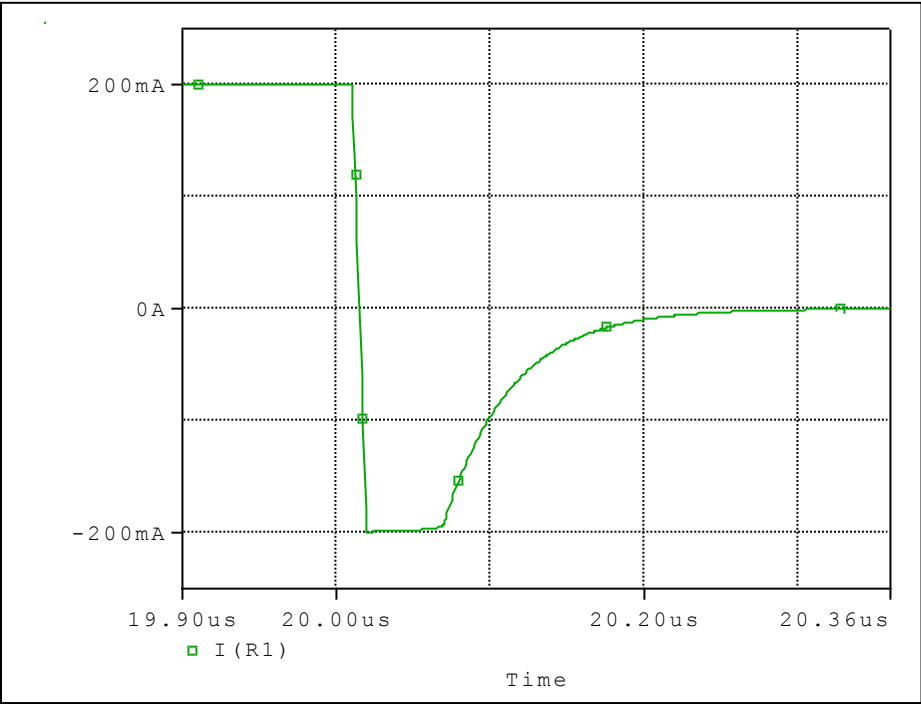


Simulation Result

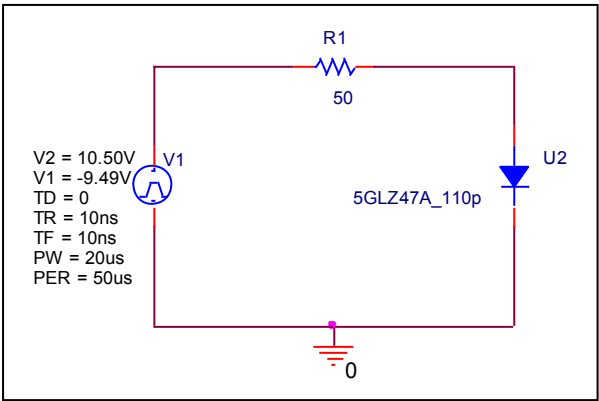
V_{rev} (V)	C_j (pF) Measurement	C_j (pF) Simulation	%Error
0	215.800	215.800	0.000
1	76.400	76.090	0.406
2	57.000	57.400	-0.702
5	39.500	39.100	1.013
10	29.500	29.100	1.356
20	22.100	21.600	2.262
50	14.700	14.600	0.680

Reverse Recovery Characteristic

Circuit Simulation Result



Evaluation Circuit

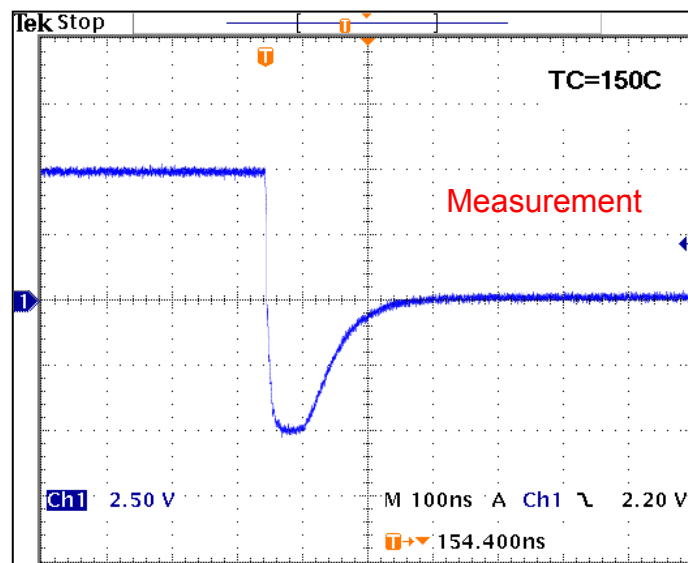


Compare Measurement vs. Simulation

	Measurement		Simulation		%Error
trj	54.00	ns	54.10	ns	-0.185
trb	100.00	ns	99.50	ns	0.500

Reverse Recovery Characteristic

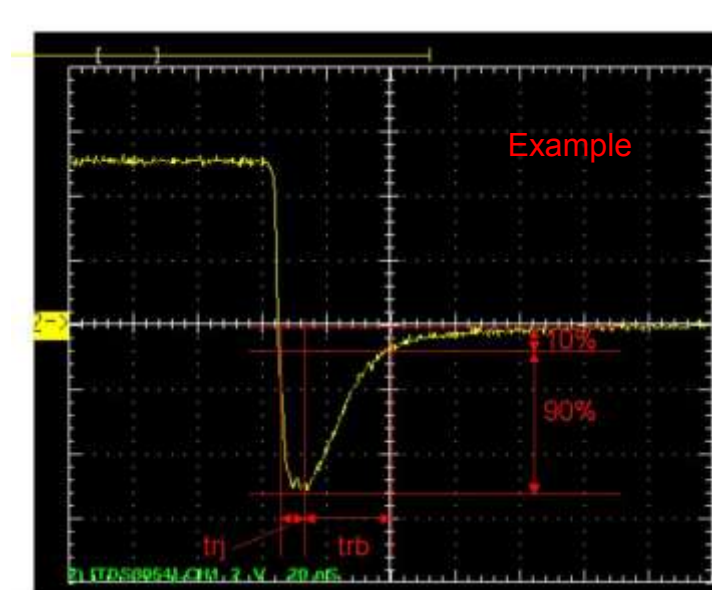
Reference



$T_{rj} = 54 \text{ (ns)}$

$T_{rb} = 100 \text{ (ns)}$

Conditions: $I_{fwd} = I_{rev} = 0.2 \text{ (A)}$, $R_I = 50$



Relation between t_{rj} and t_{rb}